

INFORMATION DISCLOSURE CITATION PTO-1449			CUSTOMER NUMBER 45114		ATTORNEY'S DKT No. H1105D		APPLICATION No. 10/602,061	
					APPLICANT(S) Shibly S. Ahmed et al.			
					FILING DATE June 24, 2003		GROUP 2812	

U.S. PATENT DOCUMENTS						
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
RP	6,472,258	10/2002	Adkisson et al.	438	192	

FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						Yes	No

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)	

EXAMINER <i>Ron Ampy</i>	DATE CONSIDERED <i>4-26-05</i>
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INFORMATION DISCLOSURE CITATION PTO-1449		Customer Number 26615		ATTORNEY'S DKT No. H1105D		APPLICATION No. 10/602,061	
				APPLICANT(S) Shibly S. AHMED et al.			
				FILING DATE June 24, 2003		GROUP <u>Unassigned</u> 2812	

U.S. PATENT DOCUMENTS						
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
RP	5,563,082	10-08-96	Mukai	437	41	12-23-94
RP	6,413,802 B1	07-02-02	Hu et al.	438	151	10-23-00

FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						Yes	No

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)	
RP	Leland Chang et al.: "Gate Length Scaling and Threshold Voltage Control of Double-Gate MOSFETs," IEDM, December 10, 2000, pages 719-722.

EXAMINER <i>Rm Pompey</i>	DATE CONSIDERED 4-26-05
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).